

RENESAS TECHNICAL UPDATE

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Renesas Electronics Corporation

Product Category	System LSI	Document No.	TN-RIN-A021A/E	Rev.	1.00
Title	Notification of R-IN32M3 Series User's Manual: Board design edition (Rev. 2.04 to Rev. 3.00) Revised contents: Corrections and new functions		Information Category	Technical Notification	
Applicable Product	See following	Lot No.	Reference Document	R-IN32M3 Series User's Manual: Board design edition R-IN32M3-EC R-IN32M3-CL Rev.3.00 (R18UZ0021EJ0300)	
		All lots			

R-IN32M3 Series User's Manual: Board design edition (for R-IN32M3-EC and R-IN32M3-CL) Rev. 3.00 (R18UZ0021EJ0300) has been released on Renesas website. For details, see "2. Documentation Updates" below.

1 Applicable Product

Product Type	Model Marking	Product Code
R-IN32M3-EC	MC-10287F1	MC-10287F1-HN4-A
		MC-10287F1-HN4-M1-A
	MC-10287BF1	MC-10287BF1-HN4-A
		MC-10287BF1-HN4-M1-A
R-IN32M3-CL	D60510F1	UPD60510F1-HN4-A
		UPD60510F1-HN4-M1-A
	D60510BF1	UPD60510BF1-HN4-A
		UPD60510BF1-HN4-M1-A

2 Documentation Updates

(1/2)

No.	Applicable Item (Rev. 3.00 Section)	Applicable Page (Rev. 3.00)	Contents
1	1.1 Definition of Pin Handling and Symbols in This Manual	1	Complement
2	3.3 Oscillation Circuit Configuration Example	8	Expression alignment
3	3.3 Oscillation Circuit Configuration Example	8	Complement
4	4.1 Recommended Configuration of Filter	9	Expression alignment
5	5.1 Built-in Regulator Used	11	Complement
6	5.1 Built-in Regulator Used	12	Complement
7	5.2 Built-in Regulator Unused	13	Complement
8	6. GPIO Port Pins	14	Errors corrected
9	7. Ethernet PHY Pins (R-IN32M3-EC Only)	15	Complement
10	7.1 Ethernet PHY Power Supply Pins	15	Errors corrected
11	7.2 100Base-TX Pins	16	Complement
12	7.2 100Base-TX Pins	17	Errors corrected
13	7.2 100Base-TX Pins	17	Complement
14	7.3 100Base-FX Pins (Optical Fiber)	20	Errors corrected
15	8. GMII Pins (R-IN32M3-CL Only)	21	Expression alignment
16	8.2 Circuit Design around GMII	22	Errors corrected
17	9. CC-Link Pins	24	Errors corrected
18	11. External MCU/Memory Interface Pins	26	Complement
19	11.1.1 Asynchronous SRAM Interface Mode	28	Expression alignment
20	11.1.2 Synchronous SRAM Interface Mode	30	Expression alignment
21	11.1.3 Synchronous SRAM-Type Transfer Mode	32	Expression alignment
22	11.2 External Memory Interface	34	Expression alignment
23	11.2.1.1 Connection Example with SRAM	35	Expression alignment
24	11.2.2.1 Connection Example with SRAM	38	Expression alignment
25	11.2.2.2 Connection Example with Paged ROM	39	Expression alignment
26	12. Serial Flash ROM Connection Pins	37	Complement
27	13. Asynchronous Serial Interface J Connection Pins	38	Complement
28	14. I ² C Connection Pins	39	Complement
29	15. EtherCAT EEPROM I ² C Connection Pins (R-IN32M3-EC Only)	40	Complement
30	16. CAN Pins	41	Complement
31	17. JTAG/Trace Pins	42	Complement

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No	Applicable Item (Rev. 9.01 Section)	Applicable Page (Rev. 9.01)	Contents
32	17. JTAG/Trace Pins	43	Complement
33	17. JTAG/Trace Pins	44	Complement
34	22. IBIS Information	51	Errors corrected
35	23.1 R-IN32M3-EC	52	Errors corrected
36	23.2 R-IN32M3-CL	52	Errors corrected
37	24. Guide to Thermal Design	53 to 61	Complement

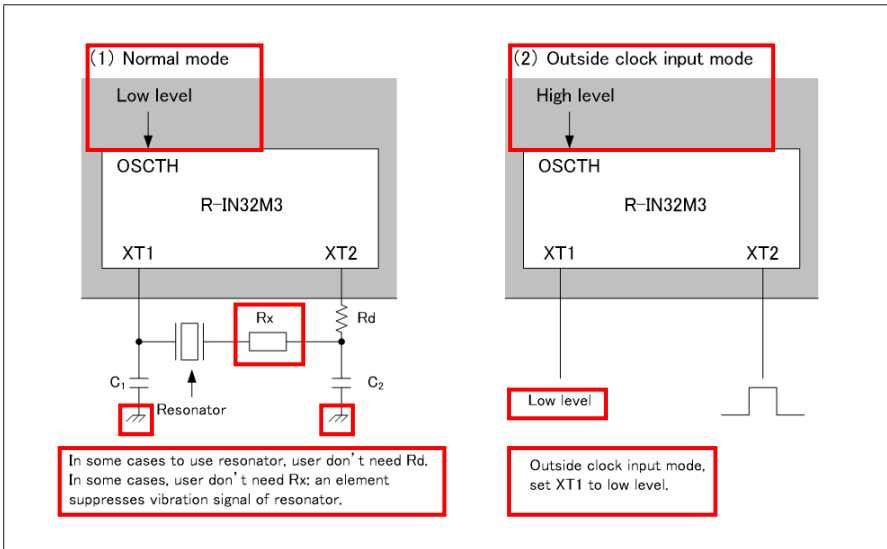
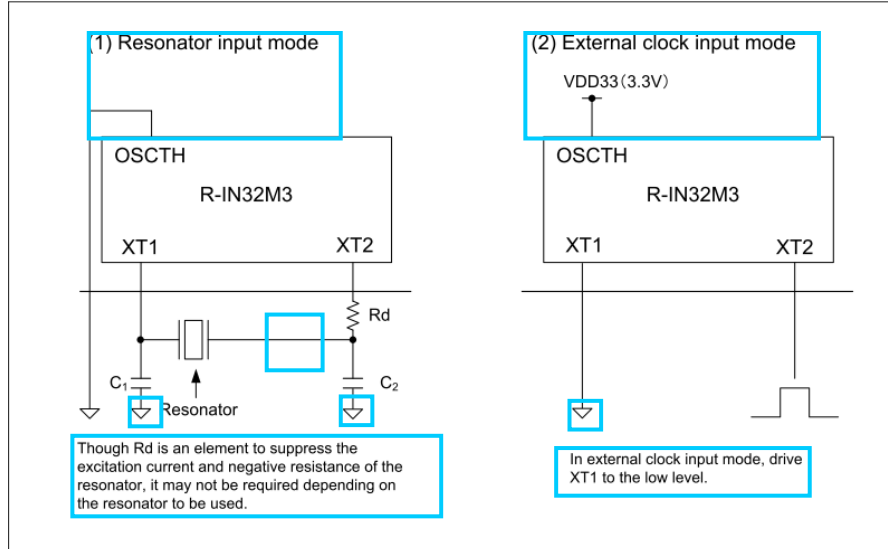
No.1 1.1 Definition of Pin Handling and Symbols in This Manual

“1.1 Definition of Pin Handling and Symbols in This Manual” was newly added.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
1	(Not described)	1	[1.1 Definition of Pin Handling and Symbols in This Manual]

No.2 3.3 Oscillation Circuit Configuration Example

Pin handling and the GND description in Figure 3.2 were modified.

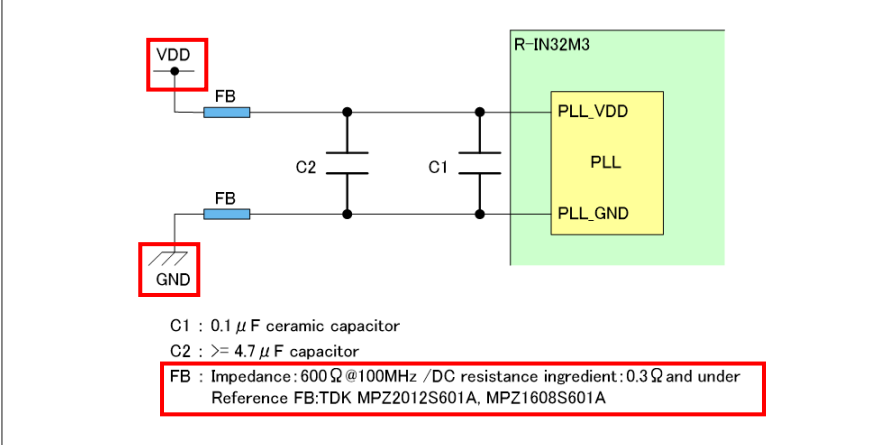
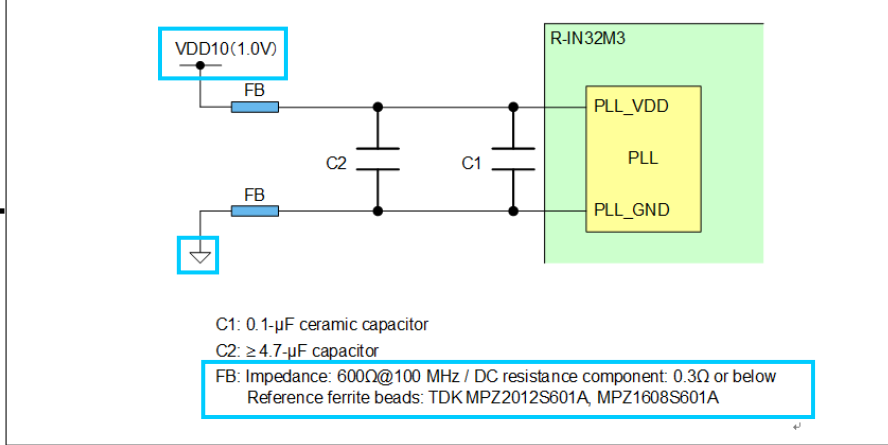
V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
7	<p>[3.3 Oscillation circuit configuration example]</p>  <p>Figure 3.2 Configuration example of the oscillation circuit</p>	7	<p>[3.3 Oscillation Circuit Configuration Example]</p>  <p>Figure 3.2 Configuration Example of the Oscillation Circuit</p>

No.3 3.3 Oscillation Circuit Configuration Example

Caution on a resonator was modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
7	<p>[3.3 Oscillation circuit configuration example] [Figure 3.2 Configuration example of the oscillation circuit]</p> <p>Caution R-IN32M3's input is fixed 25MHz. Load of resonator should be 8pF or lower. But it depends on the resonator and the design situation. Please consult the design information given by the resonator manufacturer</p>	7	<p>[3.3 Oscillation Circuit Configuration Example] [Figure 3.2 Configuration Example of the Oscillation Circuit]</p> <p>Caution. The input of the R-IN32M3 is fixed to 25 MHz. When a resonator is to be used, contact the resonator manufacturer and ask for a corresponding part number and external constants. Renesas recommends the following oscillator and resonator manufacturers.</p> <ul style="list-style-type: none"> • Nihon Dempa Kogyo Co., Ltd. (NDK) URL: http://www.ndk.com/jp/index.html/ • KYOCERA Crystal Device Corporation URL: http://www.kyocera-crystal.jp/

No.4 4.1 Recommended Configuration of Filter
Pin handling and the GND description in Figure 4.1 were modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
8	<p>[4.1 Recommended FILTER composition]</p>  <p>C1 : 0.1 μF ceramic capacitor C2 : \geq 4.7 μF capacitor FB : Impedance: 600 Ω @100MHz /DC resistance ingredient: 0.3 Ω and under Reference FB: TDK MPZ2012S601A, MPZ1608S601A</p> <p>Figure 4.1 Recommended FILTER composition</p>	8	<p>[4.1 Recommended Configuration of Filter]</p>  <p>C1 : 0.1-μF ceramic capacitor C2 : \geq 4.7-μF capacitor FB : Impedance: 600Ω@100 MHz / DC resistance component: 0.3Ω or below Reference ferrite beads: TDK MPZ2012S601A, MPZ1608S601A</p> <p>Figure 4.1 Recommended Configuration of Filter</p>

No.5 5.1 Built-in Regulator Used

Pin handling and the GND description in Figure 5.1 were modified. The description on the capacitor substitution method was added.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
10	<p>[5.1 Built-in regulator used]</p> <p>Figure 5.1 Wiring example of the regulator unit (internal regulator used)</p>	10	<p>[5.1 Built-in Regulator Used]</p> <p>Figure 5.1 Wiring Example of the Regulator Unit (Built-in Regulator Used)</p> <p>If tantalum capacitors are not available, it is possible to use a resistor and a ceramic capacitor for C1, and a ceramic capacitor for C2.</p>

No.6 5.1 Built-in Regulator Used

Table 5.1 was added to complement the list of the recommended parts.

V2.04		V3.00																									
Page	Description Contents	Page	Revised Contents																								
11	<p>[5.1 Built-in regulator used] Use recommended parts</p> <ul style="list-style-type: none"> • D1 : Schottky diode (STPS1L30UPBF, Vishay) • L1 : Inductor 10μH (VLCF5028T provided by TDK) • C1, C2 : Capacitor 22μF Tantal (ESR = 300mΩ), PSLB21A226M, NEC Tokin 	11	<p>[5.1 Built-in Regulator Used] [Table 5.1 List of Recommended Parts for Use]</p> <table border="1"> <thead> <tr> <th>Parts</th> <th>Type</th> <th>Characteristics</th> <th>Recommend Ports</th> </tr> </thead> <tbody> <tr> <td>D1</td> <td>Schottky diode</td> <td>30 V, 1 A</td> <td>STPS1L30UPBF (ST)</td> </tr> <tr> <td>L1</td> <td>Inductor</td> <td>10 uH</td> <td>VLC5028T (TDK)</td> </tr> <tr> <td>C1, C2</td> <td>Tantalum capacitor</td> <td>22 uF±20% ESR: 75 to 300 mΩ</td> <td>PSLB21A226M (NEC TOKIN)</td> </tr> <tr> <td>C1a, C2a</td> <td>Ceramic capacitor</td> <td>22 uF±10%</td> <td>GRM32ER71A226KE20L (Murata)</td> </tr> <tr> <td>R</td> <td>Resistor</td> <td>100 mΩ±1%</td> <td>MCR18EZHLR100 (ROHM)</td> </tr> </tbody> </table>	Parts	Type	Characteristics	Recommend Ports	D1	Schottky diode	30 V, 1 A	STPS1L30UPBF (ST)	L1	Inductor	10 uH	VLC5028T (TDK)	C1, C2	Tantalum capacitor	22 uF±20% ESR: 75 to 300 mΩ	PSLB21A226M (NEC TOKIN)	C1a, C2a	Ceramic capacitor	22 uF±10%	GRM32ER71A226KE20L (Murata)	R	Resistor	100 mΩ±1%	MCR18EZHLR100 (ROHM)
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No.7 5.2 Built-in Regulator Unused

Pin handling and the GND description in Figure 5.3 were modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
12	<p>[5.2 Built-in regulator unused]</p> <p>Figure 5.3 Wiring example of the regulator unit (internal regulator is not used)</p>	12	<p>[5.2 Built-in Regulator Unused]</p> <p>Figure 5.3 Wiring Example of the Regulator Unit (Internal Regulator is Not Used)</p> <p>Note. Supply stable power supply.</p>

No.8 6. GPIO Port Pins

The reference in separate user's manuals, modified

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
13	<p>[6. GPIO port pins] GPIO is general purpose IO port. Regarding internal structure, please refer below document. R-IN32M3-EC: User's Manual R-IN32M3-EC 2.3.5 Port Signals R-IN32M3-CL: User's Manual R-IN32M3-CL 2.5.5 Port Signals</p>	13	<p>[6. GPIO Port Pins] GPIO is a general-purpose I/O port. As for the internal configuration, see the section in the following document. R-IN32M3-EC: User's Manual R-IN32M3-EC "2.3.6 Port Signals" R-IN32M3-CL: User's Manual R-IN32M3-CL "2.5.6 Port Signals"</p>

No.9 7. Ethernet PHY Pins (R-IN32M3-EC Only)

The description that this section was for the R-IN32M3-EC only was added to the section title.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
14	[7. Ethernet PHY pins]	15	[7. Ethernet PHY Pins (R-IN32M3-EC Only)]

No.10 7.1 Ethernet PHY Power Supply Pins

Pin names of Rx/Tx analog power supply pins and the description of power supply pins were modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
14	[7.1 Ethernet PHY power supply pins]	14	[7.1 Ethernet PHY Power Supply Pins]

Figure 7.1 Wiring example of the regulator unit

Figure 7.1 Decoupling Capacitors for Power Supply

No.11 7.2 100Base-TX Pins

Pin handling and the GND description in Figure 7.2 were modified. Remark and Notes were moved to outside of the figure frame.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
15	<p>[7.2 100Base -TX pins]</p> <p>Figure 7.2 Connection example R-IN32M3-EC and RJ-45 connector(pulse transformer built-in)</p>	15	<p>[7.2 100Base-TX Pins]</p> <p>Figure 7.2 Connection Example of R-IN32M3-EC and RJ-45 Connector (Pulse Transformer Incorporated)</p> <p>Remark. x = 0 or 1</p> <p>Notes 1. Same potential with VDDACB and VDD33ESD 2. Same potential with AGND</p>

No.12 7.2 100Base-TX Pins

Pin handling and the GND description in Figure 7.3 were modified. Remark and Notes were moved to outside of the figure frame.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
16	<p>[7.2 100Base -TX pins]</p> <p>Figure 7.3 Connection example R-IN32M3-EC and Pulse transformer and RJ-45 connector</p>	16	<p>[7.2 100Base-TX Pins]</p> <p>Figure 7.3 Connection Example of R-IN32M3-EC, Pulse Transformer, and RJ-45 Connector</p> <p>Remark. x = 0 or 1</p> <p>Notes 1. Same potential with VDDACB and VDD33ESD 2. Same potential with AGND</p>

No.13 7.2 100Base-TX Pins

Note was added to R1 to R6 in Table 7.1.

V2.04				V3.00																																																																																																		
Page	Description Contents			Page	Revised Contents																																																																																																	
16	<p>[7.2 100Base -TX pins] [Table 7.1 Parts list (100Base-TX interface)]</p> <table border="1"> <thead> <tr> <th>Part</th> <th>Type</th> <th>Characteristics</th> <th>Recommended components</th> </tr> </thead> <tbody> <tr> <td>R1, R2, R3, R4</td> <td>Resistor</td> <td>49.9Ω ± 1% 1/16W</td> <td>-</td> </tr> <tr> <td>R5, R6</td> <td>Resistor</td> <td>10Ω ± 1% 1/16W</td> <td>-</td> </tr> <tr> <td>R7, R8, R9, R10</td> <td>Resistor</td> <td>75Ω ± 1% 1/16W</td> <td>-</td> </tr> <tr> <td>C1</td> <td>Capacitor</td> <td>10nF - 100nF</td> <td>-</td> </tr> <tr> <td>C2</td> <td>Capacitor</td> <td>10nF - 100nF</td> <td>-</td> </tr> <tr> <td>C3</td> <td>Capacitor</td> <td>10nF - 22nF</td> <td>-</td> </tr> <tr> <td>C4</td> <td>Capacitor</td> <td>10nF - 22nF</td> <td>-</td> </tr> <tr> <td>C5</td> <td>Capacitor</td> <td>4.7nF ± 10%</td> <td>-</td> </tr> <tr> <td rowspan="2">Transformer</td> <td>One channel</td> <td></td> <td>Pulse Electronics H1012NL, H1102NL</td> </tr> <tr> <td>Twochannel</td> <td></td> <td>Pulse Electronics H1270N+, HX1294</td> </tr> <tr> <td>RJ45 with integrated magnetics</td> <td>Two channel</td> <td></td> <td>Pulse Electronics JG0-0031NL</td> </tr> </tbody> </table>			Part	Type	Characteristics	Recommended components	R1, R2, R3, R4	Resistor	49.9Ω ± 1% 1/16W	-	R5, R6	Resistor	10Ω ± 1% 1/16W	-	R7, R8, R9, R10	Resistor	75Ω ± 1% 1/16W	-	C1	Capacitor	10nF - 100nF	-	C2	Capacitor	10nF - 100nF	-	C3	Capacitor	10nF - 22nF	-	C4	Capacitor	10nF - 22nF	-	C5	Capacitor	4.7nF ± 10%	-	Transformer	One channel		Pulse Electronics H1012NL, H1102NL	Twochannel		Pulse Electronics H1270N+, HX1294	RJ45 with integrated magnetics	Two channel		Pulse Electronics JG0-0031NL	16	<p>[7.2 100Base-TX Pins] [Table 7.1 Parts List (100Base-TX interface)]</p> <table border="1"> <thead> <tr> <th>Part</th> <th>Type</th> <th>Characteristics</th> <th>Recommended Components</th> </tr> </thead> <tbody> <tr> <td>R1, R2, R3, R4</td> <td>Resistor</td> <td>49.9Ω±1% 1/16W ^{Note}</td> <td>-</td> </tr> <tr> <td>R5, R6</td> <td>Resistor</td> <td>10Ω±1% 1/16W ^{Note}</td> <td>-</td> </tr> <tr> <td>R7, R8, R9, R10</td> <td>Resistor</td> <td>75Ω±1% 1/16W</td> <td>-</td> </tr> <tr> <td>C1</td> <td>Capacitor</td> <td>10 nF to 100 nF</td> <td>-</td> </tr> <tr> <td>C2</td> <td>Capacitor</td> <td>10 nF to 100 nF</td> <td>-</td> </tr> <tr> <td>C3</td> <td>Capacitor</td> <td>10 nF to 2 2 nF</td> <td>-</td> </tr> <tr> <td>C4</td> <td>Capacitor</td> <td>10 nF to 22 nF</td> <td>-</td> </tr> <tr> <td>C5</td> <td>Capacitor</td> <td>4.7 nF±10%</td> <td>-</td> </tr> <tr> <td>Pulse transformer</td> <td>One channel</td> <td></td> <td>Pulse Electronics H1012NL, H1102NL</td> </tr> <tr> <td></td> <td>Two channels</td> <td></td> <td>Pulse Electronics H1270N+, HX1294</td> </tr> <tr> <td>RJ-45 connector (Pulse transformer incorporated)</td> <td>Two channels</td> <td></td> <td>Pulse Electronics JG0-0031NL</td> </tr> </tbody> </table> <p>Note: We recommend 1/8W when using in harsh environments, such as at high temperature.</p>			Part	Type	Characteristics	Recommended Components	R1, R2, R3, R4	Resistor	49.9Ω±1% 1/16W ^{Note}	-	R5, R6	Resistor	10Ω±1% 1/16W ^{Note}	-	R7, R8, R9, R10	Resistor	75Ω±1% 1/16W	-	C1	Capacitor	10 nF to 100 nF	-	C2	Capacitor	10 nF to 100 nF	-	C3	Capacitor	10 nF to 2 2 nF	-	C4	Capacitor	10 nF to 22 nF	-	C5	Capacitor	4.7 nF±10%	-	Pulse transformer	One channel		Pulse Electronics H1012NL, H1102NL		Two channels		Pulse Electronics H1270N+, HX1294	RJ-45 connector (Pulse transformer incorporated)	Two channels		Pulse Electronics JG0-0031NL
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RJ-45 connector (Pulse transformer incorporated)	Two channels		Pulse Electronics JG0-0031NL																																																																																																			

No.14 7.3 100Base-FX Pins (Optical Fiber)

Pin handling and the GND description in Figure 7.7 were modified. Remark was moved to outside of the figure frame.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
19	<p>[7.3 100Base-FX pins (Optical fiber)]</p> <p>Figure 7.7 Interface circuit with optical transceiver</p>	19	<p>[7.3 100Base-FX Pins (Optical Fiber)]</p> <p>Figure 7.7 Interface Circuit with Optical Transceiver</p> <p>Remark: x = 0 or 1</p>

No.15 8. GMII Pins (R-IN32M3-CL Only)

Pin handling in Figure 8.1 was modified. Remark was moved to outside of the figure frame.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
20	<p>[8. GMII pins (R-IN32M3-CL only)]</p> <p>3.3V 4.7kΩ</p> <p>ETH_MDC ETH_MDIO</p> <p>MDC MDIO</p> <p>Wires are recommended to be short and the same length.</p> <p>GND Shield GND Shield</p> <p>ETHm_TXC ETHm_GTXC ETHm_TXDx ETHm_TXEN ETHm_TXER</p> <p>TX_CLK GTX_CLK TXDx* TX_EN TX_ER</p> <p>Damping resistor : 33Ω ±5%</p> <p>GND Shield</p> <p>ETHm_RXC ETHm_RXDx ETHm_RXDV ETHm_RXER</p> <p>RX_CLK RXDx* RX_DV RX_ER</p> <p>ETHm_COL ETHm_CRS</p> <p>COL CRS</p> <p>R-IN32M3-CL</p> <p>Gigabit Ethernet PHY</p> <p>RJ45 Connector</p> <p>Remark : m = 0, 1, x = 0-7</p>	20	<p>[8. GMII Pins (R-IN32M3-CL Only)]</p> <p>VDD33 (3.3 V) 4.7kΩ</p> <p>ETH_MDC ETH_MDIO</p> <p>MDC MDIO</p> <p>Wires are recommended to be short and equal-length.</p> <p>GND shield GND shield</p> <p>ETHm_TXC ETHm_GTXC ETHm_TXDx ETHm_TXEN ETHm_TXER</p> <p>TX_CLK GTX_CLK TXDx* TX_EN TX_ER</p> <p>Damping resistor: 33Ω±5%</p> <p>GND shield</p> <p>ETHm_RXC ETHm_RXDx ETHm_RXDV ETHm_RXER</p> <p>RX_CLK RXDx* RX_DV RX_ER</p> <p>ETHm_COL ETHm_CRS</p> <p>COL CRS</p> <p>R-IN32M3-CL</p> <p>Gigabit Ethernet PHY</p> <p>RJ45 connector</p> <p>Figure 8.1 Connection Image of R-IN32M3-CL and Gigabit Ethernet PHY</p> <p>Remark: m = 0, 1, x = 0 to 7</p>

No.16 8.2 Circuit Design around GMII

The description of the number for Ethernet ports was modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
21	<p>[8.2 Circuit design around GMII]</p> <p>Please be set to the same address as the port number of the R-IN32M3-CL and The PHY address. Connect to the PHY assigned address¹ to MAC port¹, And Connect to the PHY assigned address² to MAC port²</p>	21	<p>[8.2 Circuit Design around GMII]</p> <ul style="list-style-type: none"> • For PHY address Set to the same address as the port number of the R-IN32M3-CL to the PHY address. Connect the PHY assigned to address 0 to MAC port 0, and connect the PHY assigned to address 1 to MAC port 1.

No.17 9. CC-Link Pins

Pin handling and the GND description in Figure 9.1 were modified. The name for CC-Link clock pins was modified. Note 3 was added.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
23	<p>[9. CC-Link pins]</p> <p>Figure 9.1 The connection example for CC-Link Remote device station</p> <p>Note1</p> <p>Note2</p>	<p>[9. CC-Link Pins]</p> <p>Figure 9.1 Connection Example for CC-Link Remote Device Station</p> <p>Notes 1.</p> <p>2.</p> <p>3. This pin is multiplexed with CC-Link (intelligent device station).</p>	

No.18 11. External MCU/Memory Interface Pins

As the mode setting pin, the ADMUXMODE pin was added. Note when accessing the CC-Link IE field was added.

V2.04		V3.00																																																												
Page	Description Contents	Page	Revised Contents																																																											
25	<p>[11. External MPU/memory interface pins]</p> <p>The connection mode is decided as Table 11.1 by the signal level of the MEMIFSEL pin, MEMCSEL pin and HIFSYNC pin.</p> <p>Table 11.1 The mode selection of external MPU/memory connection</p> <table border="1"> <thead> <tr> <th colspan="3">Mode setting</th> <th rowspan="2">The connection mode to external parts</th> </tr> <tr> <th>MEMIFSEL</th> <th>MEMCSEL</th> <th>HIFSYNC</th> </tr> </thead> <tbody> <tr> <td rowspan="2">Low</td> <td>Low</td> <td>-</td> <td>External memory interface Asynchronous SRAM MEMC</td> </tr> <tr> <td>High</td> <td>-</td> <td>External memory interface Synchronous SRAM MEMC</td> </tr> <tr> <td rowspan="4">High</td> <td rowspan="2">Low</td> <td>Low</td> <td>External MPU interface Asynchronous SRAM interface</td> </tr> <tr> <td>High</td> <td>External MPU interface Synchronous SRAM interface</td> </tr> <tr> <td rowspan="2">High</td> <td>Low</td> <td>Prohibition of a setup</td> </tr> <tr> <td>High</td> <td>External MPU interface Synchronous SRAM type transmission mode</td> </tr> </tbody> </table>	Mode setting			The connection mode to external parts	MEMIFSEL	MEMCSEL	HIFSYNC	Low	Low	-	External memory interface Asynchronous SRAM MEMC	High	-	External memory interface Synchronous SRAM MEMC	High	Low	Low	External MPU interface Asynchronous SRAM interface	High	External MPU interface Synchronous SRAM interface	High	Low	Prohibition of a setup	High	External MPU interface Synchronous SRAM type transmission mode	25	<p>[11. External MCU/Memory Interface Pins]</p> <p>The connection mode is decided by the signal level of the MEMIFSEL, MEMCSEL, HIFSYNC, and ADMUXMODE pins as shown in Table 11.1.</p> <p>Table 11.1 Mode Selection of External MCU/Memory Connection</p> <table border="1"> <thead> <tr> <th colspan="4">Mode Setting</th> <th rowspan="2">External Connection Mode</th> </tr> <tr> <th>MEMIFSEL</th> <th>MEMCSEL</th> <th>HIFSYNC</th> <th>ADMUXMODE</th> </tr> </thead> <tbody> <tr> <td rowspan="2">Low</td> <td>Low</td> <td>-</td> <td>-</td> <td>External memory interface Asynchronous SRAM MEMC</td> </tr> <tr> <td>High</td> <td>-</td> <td>-</td> <td>External memory interface Synchronous burst access MEMC</td> </tr> <tr> <td rowspan="4">High</td> <td rowspan="2">Low</td> <td>Low</td> <td>-</td> <td>External MCU interface Asynchronous SRAM interface mode</td> </tr> <tr> <td>High</td> <td>-</td> <td>External MCU interface Synchronous SRAM interface mode <small>Note</small></td> </tr> <tr> <td rowspan="2">High</td> <td>Low</td> <td>-</td> <td>Setting prohibited</td> </tr> <tr> <td>High</td> <td>Low</td> <td>High</td> <td>External MCU interface Synchronous SRAM-type transfer mode (address/data multiplexed)</td> </tr> </tbody> </table> <p>Note: Before access to the CC-Link IE field, select the synchronous SRAM interface mode (MEMIFSEL high, MEMCSEL low, HIFSYNC high). (The CC-Link IE field is incorporated only in the R-IN32M3-CL.)</p>	Mode Setting				External Connection Mode	MEMIFSEL	MEMCSEL	HIFSYNC	ADMUXMODE	Low	Low	-	-	External memory interface Asynchronous SRAM MEMC	High	-	-	External memory interface Synchronous burst access MEMC	High	Low	Low	-	External MCU interface Asynchronous SRAM interface mode	High	-	External MCU interface Synchronous SRAM interface mode <small>Note</small>	High	Low	-	Setting prohibited	High	Low	High	External MCU interface Synchronous SRAM-type transfer mode (address/data multiplexed)
Mode setting			The connection mode to external parts																																																											
MEMIFSEL	MEMCSEL	HIFSYNC																																																												
Low	Low	-	External memory interface Asynchronous SRAM MEMC																																																											
	High	-	External memory interface Synchronous SRAM MEMC																																																											
High	Low	Low	External MPU interface Asynchronous SRAM interface																																																											
		High	External MPU interface Synchronous SRAM interface																																																											
	High	Low	Prohibition of a setup																																																											
		High	External MPU interface Synchronous SRAM type transmission mode																																																											
Mode Setting				External Connection Mode																																																										
MEMIFSEL	MEMCSEL	HIFSYNC	ADMUXMODE																																																											
Low	Low	-	-	External memory interface Asynchronous SRAM MEMC																																																										
	High	-	-	External memory interface Synchronous burst access MEMC																																																										
High	Low	Low	-	External MCU interface Asynchronous SRAM interface mode																																																										
		High	-	External MCU interface Synchronous SRAM interface mode <small>Note</small>																																																										
	High	Low	-	Setting prohibited																																																										
		High	Low	High	External MCU interface Synchronous SRAM-type transfer mode (address/data multiplexed)																																																									

No.19 11.1.1 Asynchronous SRAM Interface Mode

The description of pin handling in Figure 11.1 and Figure 11.2 was modified. The position for the HBUSCLK pin and Note was modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
26, 27	<p>[11.1.1 Asynchronous SRAM interface]</p> <p>Figure 11.1 The connection example with external MPU (32bit bus, asynchronous SRAM interface mode)</p> <p>Figure 11.2 The connection example with external MPU (16bit bus, asynchronous SRAM interface mode)</p>	28	<p>[11.1.1 Asynchronous SRAM Interface Mode]</p> <p>Figure 11.1 Connection Example of 32-Bit External MCU Interface (Asynchronous SRAM Interface Mode)</p> <p>Figure 11.2 Connection Example of 16-Bit External MCU Interface (Asynchronous SRAM Interface Mode)</p>

No.20 11.1.2 Synchronous SRAM Interface Mode

The position for the HBUSCLK pin and Note in Figure 11.3 and Figure 11.4 were modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
28	<p>[11.1.2 Synchronous SRAM interface mode]</p> <p>Figure 11.3 The connection example with external MPU (32bit bus, synchronous SRAM interface mode)</p> <p>Figure 11.4 The connection example with external MPU (16bit bus, synchronous SRAM interface mode)</p>	30	<p>[11.1.2 Synchronous SRAM Interface Mode]</p> <p>Figure 11.3 Connection Example of 32-Bit External MCU Interface (Synchronous SRAM Interface Mode)</p> <p>Figure 11.4 Connection Example of 16-Bit External MCU Interface (Synchronous SRAM Interface Mode)</p>

No.21 Synchronous SRAM-Type Transfer Mode

The description of pin handling in Figure 11.5 and Figure 11.6 was modified. The position for the HBUSCLK pin and Note was modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
30	<p>[11.1.3 Synchronous SRAM type transmission mode]</p> <p>Figure 11.5 The connection example with external MPU (32bit bus, synchronous SRAM type transmission mode)</p> <p>Figure 11.6 The connection example with external MPU (16bit bus, synchronous SRAM type transmission mode)</p>	32	<p>[11.1.3 Synchronous SRAM-Type Transfer Mode]</p> <p>Figure 11.5 Connection Example of 32-Bit External MCU Interface (Synchronous SRAM-Type Transfer Mode)</p> <p>Figure 11.6 Connection Example of 16-Bit External MCU Interface (Synchronous SRAM-Type Transfer Mode)</p>

No.22 11.2 External Memory Interface

As it was not needed, the description on the MEMIFSEL pin was deleted.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
32	<p>[11.2 External memory interface] This section describes about the connection to an external memory. The connection mode of the external memory interface depends on the signal levels of the MEMCSEL pin and MEMIFSEL pin. (Please refer the Table 11.1.)</p>	34	<p>[11.2 External Memory Interface] This section describes the connection as a master device to an external memory. The operating connection mode of the external memory interface depends on the level of the signal on the MEMIFSEL pin (see Table 11.1).</p>

No.23 11.2.1.1 Connection Example with SRAM

Remarks in Figure 11.7 and Figure 11.8 were moved to outside of the figure frame.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
32	<p>[11.2.1.1 SRAM connection example]</p> <p>備考 n = 0-3</p> <p>Figure 11.7 Example of Connection with SRAM (32bit bus, asynchronous SRAM MEMC)</p> <p>備考 n = 0-3</p> <p>Figure 11.8 Example of Connection with SRAM (16bit bus, asynchronous SRAM MEMC)</p>	35	<p>[11.2.1.1 Connection Example with SRAM]</p> <p>Figure 11.7 Connection Example with 32-Bit SRAM (Asynchronous SRAM MEMC)</p> <p>Figure 11.8 Connection Example with 16-Bit SRAM (Asynchronous SRAM MEMC)</p> <p>Remark: n = 0 to 3</p>

No.24 11.2.2.1 Connection Example with SRAM

Remarks in Figure 11.11 and Figure 11.12 were moved to outside of the figure frame. The description of Note was modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
34	<p>[11.2.2.1 SRAM connection example]</p> <p>Figure 11.11 Example of Connection with SRAM (32bit bus, synchronous burst access MEMC)</p> <p>Figure 11.12 Example of Connection with SRAM (16bit bus, synchronous burst access MEMC)</p>	35	<p>[11.2.2.1 Connection Example with SRAM]</p> <p>Figure 11.11 Connection Example with 32-Bit SRAM (Synchronous Burst Access MEMC)</p> <p>Figure 11.12 Connection Example with 16-Bit SRAM (Synchronous Burst Access MEMC)</p> <p>Remark: n = 0 to 3</p>

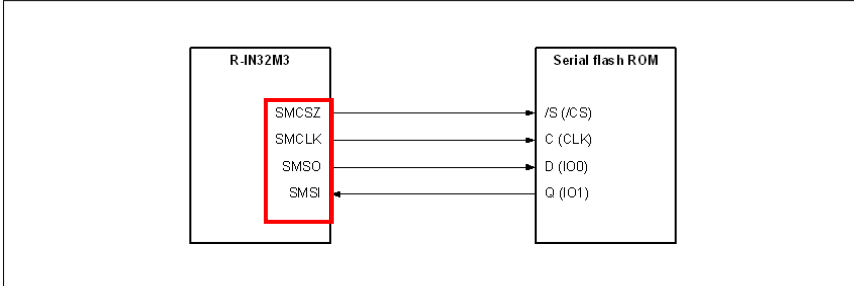
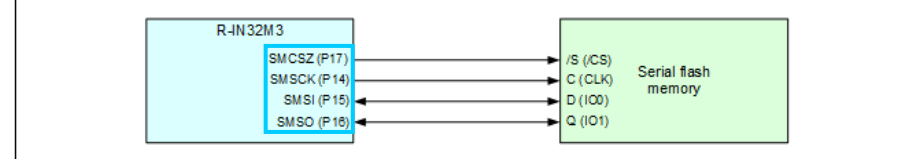
No.25 11.2.2.2 Connection Example with Paged ROM

The description of Note in Figure 11.13 and Figure 11.14 was modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
35	<p>[11.2.2.2 Page ROM Connection Example]</p> <p>Figure 11.13 Example of Connection with Page ROM (32bit bus, synchronous burst access MEMC)</p> <p>Figure 11.14 Example of Connection with Page ROM (16bit bus, synchronous burst access MEMC)</p>	36	<p>[11.2.2.2 Connection Example with Paged ROM]</p> <p>Figure 11.13 Connection Example with 32-Bit Paged ROM (Synchronous Burst Access MEMC)</p> <p>Figure 11.14 Connection Example with 16-Bit Paged ROM (Synchronous Burst Access MEMC)</p>

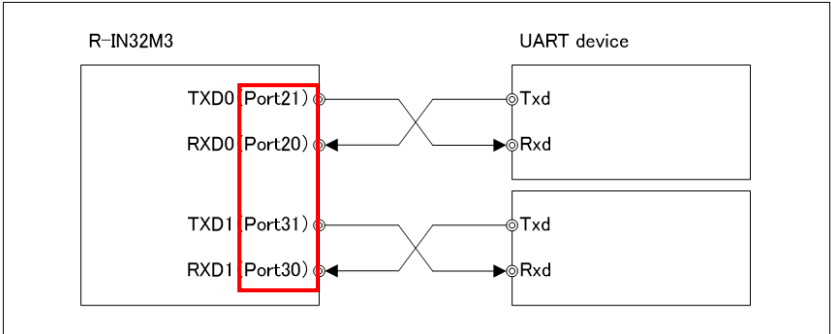
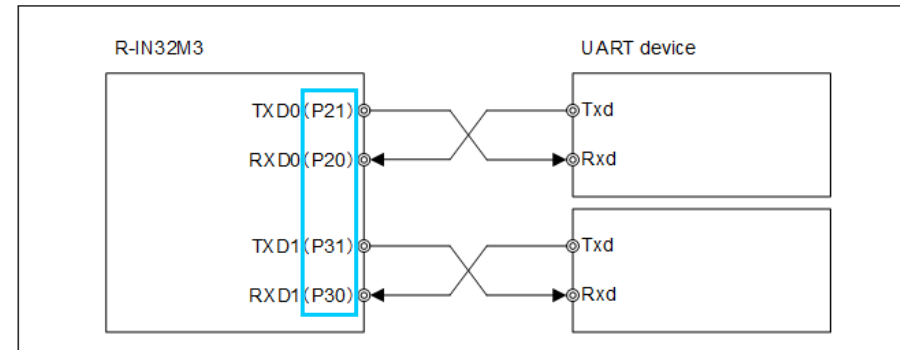
No.26 12. Serial Flash ROM Connection Pins

The name of port pin was added to the pin name in Figure 12.1.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
36	<p>[12. Serial flash ROM connection pins]</p>  <p>Figure 12.1 Connection with Serial Flash ROM</p>	37	<p>[12. Serial Flash ROM Connection Pins]</p>  <p>Figure 12.1 Connection Example with Serial Flash ROM</p>

No.27 13. Asynchronous Serial Interface J Connection Pins

The section title was modified. The name of port pin was modified in Figure 13.1.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
37	<p>[13. Asynchronous Serial Interface J(UARTJn) connection pins]</p> <p>Figure 13.1 shows a connection example between R-IN32M3 and Asynchronous Serial Interface J(UARTJn) device.</p>  <p>Figure 13.1 Connection example with the UART device</p>	38	<p>[13. Asynchronous Serial Interface J Connection Pins]</p> <p>Figure 13.1 shows a connection example between the R-IN32M3 and the asynchronous serial interface J (UARTJn) device.</p>  <p>Figure 13.1 Connection Example between R-IN32M3 and UART Device</p>

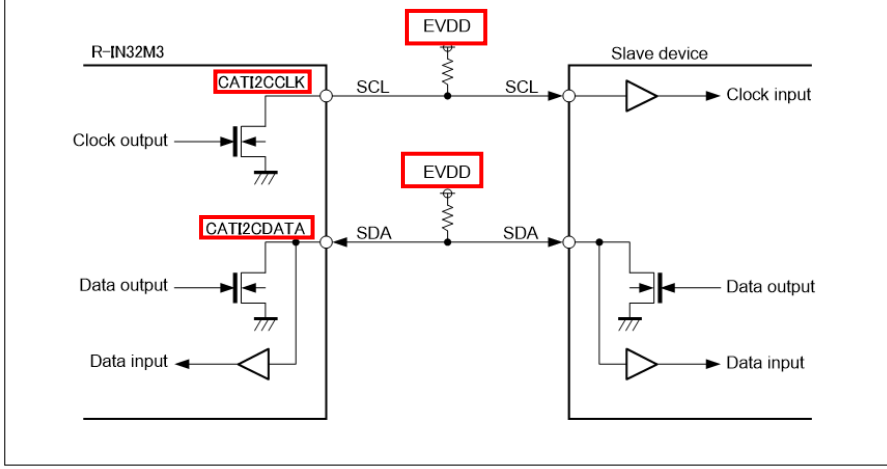
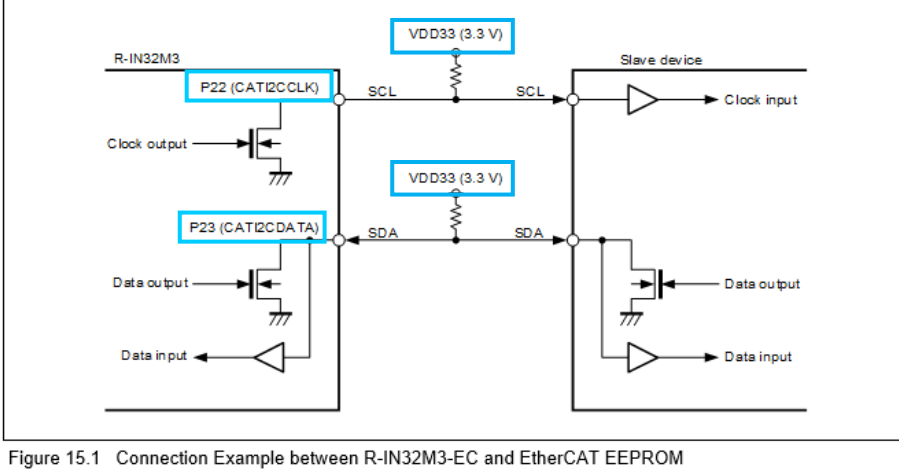
No.28 14. I²C Connection Pins

Pin handling in Figure 14.1 was modified. The name of I²C pin was added to the port pin.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
38	<p>[14. I²C connection pins]</p> <p>Figure 14.1 Connection example with the I²C Slave device</p>	39	<p>[14. I²C Connection Pins]</p> <p>Figure 14.1 Connection Example between R-IN32M3 and I²C Slave Device</p>

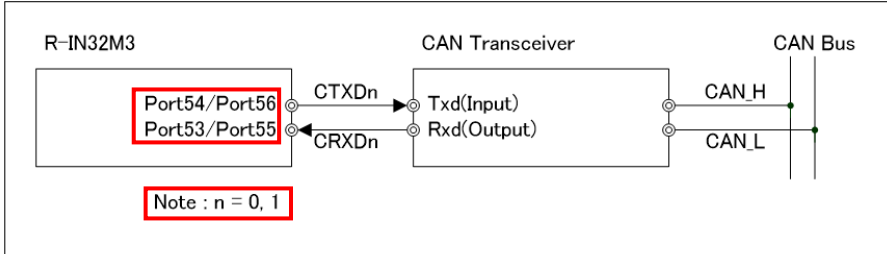
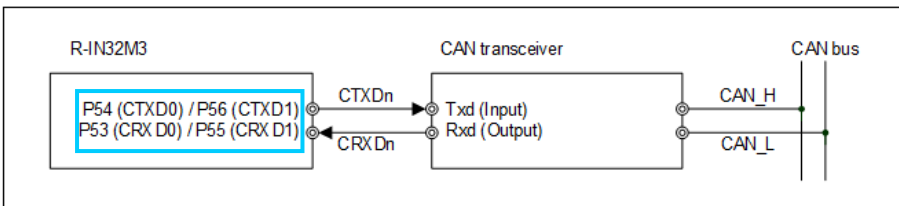
No.29 15. EtherCAT EEPROM I²C Connection Pins (R-IN32M3-EC Only)

The description of pin handling in Figure 15.1 was modified. The name of the multiplexing port was added to the EtherCAT pin.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
39	<p>[15. EtherCAT EEPROM I²C connection pins (only R-IN32M3-EC)]</p>  <p>Figure 15.1 Connection example with the EtherCAT EEPROM</p>	40	<p>[15. EtherCAT EEPROM I²C Connection Pins (R-IN32M3-EC Only)]</p>  <p>Figure 15.1 Connection Example between R-IN32M3-EC and EtherCAT EEPROM</p>

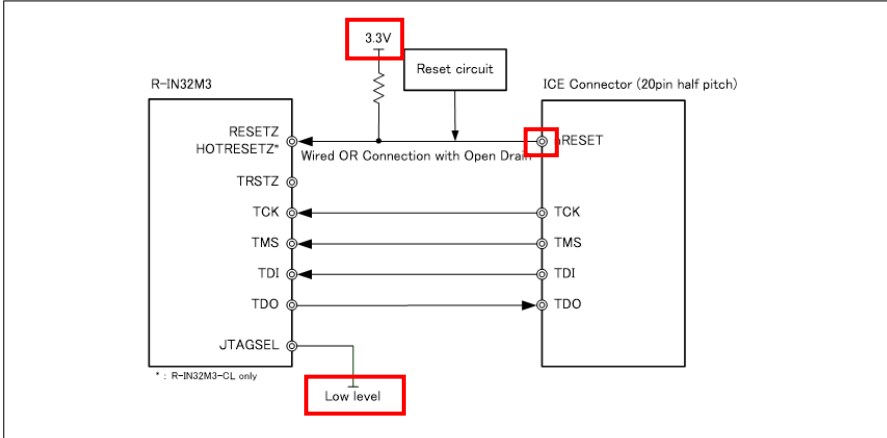
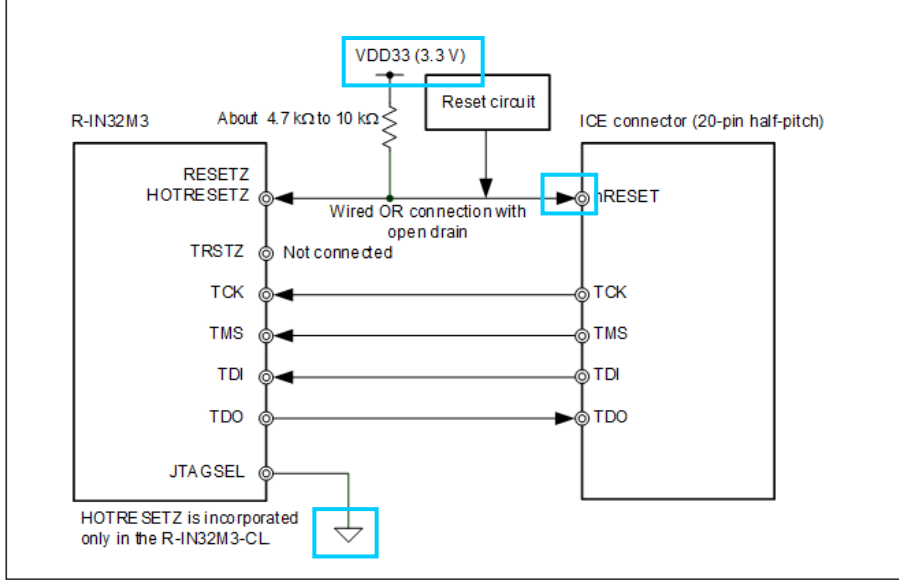
No.30 16. CAN Pins

The name of port pin was modified in Figure 16.1. The name of the CAN pin was added. Remark was moved to outside of the figure frame.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
40	<p>[16. CAN pins]</p>  <p>Note : n = 0, 1</p> <p>Figure 16.1 Connection example with the CAN Transceiver</p>	41	<p>[16. CAN Pins]</p>  <p>Figure 16.1 Connection Example between R-IN32M3 and CAN Transceiver</p> <p>Remark: n = 0 or 1</p>

No.31 17. JTAG/Trace Pins

The connection of the ICE connector to the nRESET pin in Figure 17.1 was modified. Pin handling and the GND description were modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
41	<p>[17. JTAG/trace pins]</p>  <p>Figure 17.1 JTAG interface connection example (20pin half pitch without trace)</p>	42	<p>[17. JTAG/Trace Pins]</p>  <p>Figure 17.1 Connection Example of JTAG Interface (20-Pin Half-Pitch without Trace)</p>

No.32 17. JTAG/Trace Pins

The connection of the ICE connector to the nRESET pin in Figure 17.2 was modified. The description on the wiring limitation was modified. Pin handling and the GND description were modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
42	<p>[17. JTAG/trace pins]</p> <p>Figure 17.2 JTAG interface connection example (20pin half pitch with trace)</p>	43	<p>[17. JTAG/Trace Pins]</p> <p>Figure 17.2 Connection Example of JTAG Interface (20-Pin Half-Pitch with Trace)</p>

No.33 17. JTAG/Trace Pins

The connection of the ICE connector to the nRESET pin in Figure 17.3 was modified. Pin handling and the GND description were modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
43	<p>[17. JTAG/trace pins]</p> <p>Figure 17.3 JTAG interface connection example (20pin full pitch)</p>	44	<p>[17. JTAG/Trace Pins]</p> <p>Figure 17.3 Connection Example of JTAG Interface (20-Pin Full-Pitch)</p>


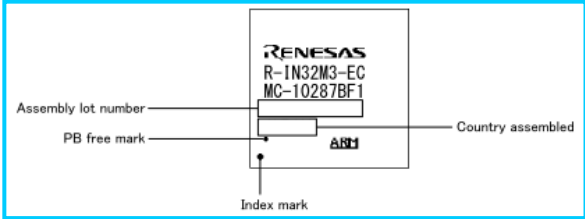
No.34 22. IBIS Information

The website was modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
50	<p>[22. IBIS Information]</p> <p>Please obtain from the following website IBIS information. http://japan.renesas.com/products/soc/assp/fa_lsi/multi_protocol_communication/r-in32m3/peer/documents.jsp</p>	51	<p>[22. IBIS Information]</p> <p>Please obtain the IBIS information from the following website. https://www.renesas.com/products/factory-automation/multi-protocol-communication.html</p>


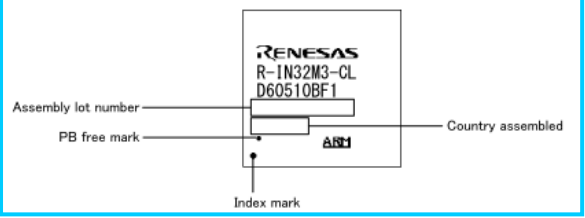
No.35 23.1 R-IN32M3-EC

The product name and the marking information of the R-IN32M3-EC were modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
51	<p>[23.1 R-IN32M3-EC] Product name: MC-10287F1-HN4-M1-A</p>  <p>Figure 23.1 R-IN32M3-EC Impress information</p>	52	<p>[23.1 R-IN32M3-EC] Product name: MC-10287BF1-HN4-A, MC-10287BF1-HN4-M1-A</p>  <p>Figure 23.1 R-IN32M3-EC Marking Information</p>

No.36 23.2 R-IN32M3-CL

The product name and the marking information of the R-IN32M3-CL were modified.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
51	<p>[23.2 R-IN32M3-CL] Product name: UPD60510F1-HN4-M1-A</p>  <p>Figure 23.2 R-IN32M3-CL Impress information</p>	52	<p>[23.2 R-IN32M3-CL] Product name: UPD60510BF1-HN4-A, UPD60510BF1-HN4-M1-A</p>  <p>Figure 23.2 R-IN32M3-CL Marking Information</p>

No.37 24. Guide to Thermal Design

The guide to the thermal design for the R-IN32M3-EC was newly added.

V2.04		V3.00	
Page	Description Contents	Page	Revised Contents
-	(Not described)	53 to 61	[24. Guide to Thermal Design]